

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L2	3174	(438/592,655,656,659,660,683).CCLS.	USPAT	2005/12/30 06:52
2	BRS	L6	904	2 and @ad<="19960716"	USPAT	2005/12/30 06:52
3	IS&R	L7	2610	(438/592,655,656,659,660,683).CCLS.	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/30 06:52
4	BRS	L8	1918	7 and @ad<="19960716"	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/30 07:30
5	BRS	L9	51	6 and (amorphous near7 silicide)	USPAT	2005/12/30 07:15
6	BRS	L10	23	8 and (amorphous near7 silicide)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/30 07:31
7	BRS	L11	0	((gate adj (dielectric insulation)) and (poly adj silicon polysilicon poly-silicon) and (amorphous adj silicide) and ((Si silicon) adj cluster)).clm.	US-PGPUB	2005/12/30 08:10
8	BRS	L12	0	((gate adj (dielectric insulation)) and (poly adj silicon polysilicon poly-silicon) and (amorphous near3 silicide) and ((Si silicon) adj cluster)).clm.	US-PGPUB	2005/12/30 08:10